

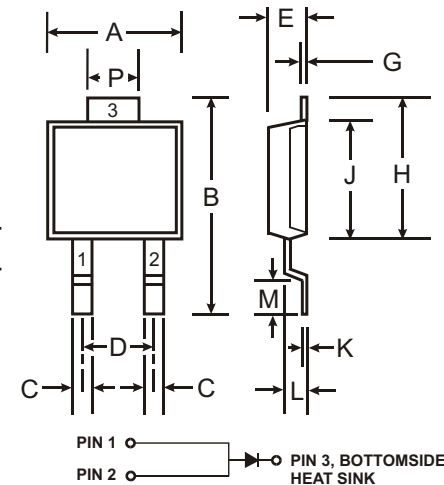
Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- Low Reverse Current
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: POWERMITE®3, Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Moisture sensitivity: Level 1 per J-STD-020A
- Polarity: See Diagram
- Marking: Type Number
- Weight: 0.072 grams (approx.)

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Note: Pins 1 & 2 must be electrically connected at the printed circuit board.

POWERMITE®3		
Dim	Min	Max
A	4.03	4.09
B	6.40	6.61
C	.889 NOM	
D	1.83 NOM	
E	1.10	1.14
G	.178 NOM	
H	5.01	5.17
J	4.37	4.43
K	.178 NOM	
L	.71	.77
M	.36	.46
P	1.73	1.83
All Dimensions in mm		

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	60	V
RMS Reverse Voltage	V _{R(RMS)}	42	V
Average Rectified Output Current (See also figure 4)	I _O	7	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method) @ T _C = 55°C	I _{FSM}	100	A
Typical Thermal Resistance Junction to Soldering Point	R _{θJS}	2.5	°C/W
Operating Temperature Range	T _J	-65 to +125	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	60	—	—	V	I _R = 0.5mA
Forward Voltage (Note 1)	V _F	—	0.49 0.38 0.57 0.46	0.52 — 0.60 —	V	I _F = 3.5A, T _J = 25°C I _F = 3.5A, T _J = 125°C I _F = 7A, T _J = 25°C I _F = 7A, T _J = 125°C
Reverse Current (Note 1)	I _R	—	5 10	200 20	μA mA	T _J = 25°C, V _R = 60V T _J = 125°C, V _R = 60V
Total Capacitance	C _T	—	375	—	pF	f = 1.0MHz, V _R = 4.0V DC

Notes: 1. Short duration test pulse used to minimize self-heating effect.

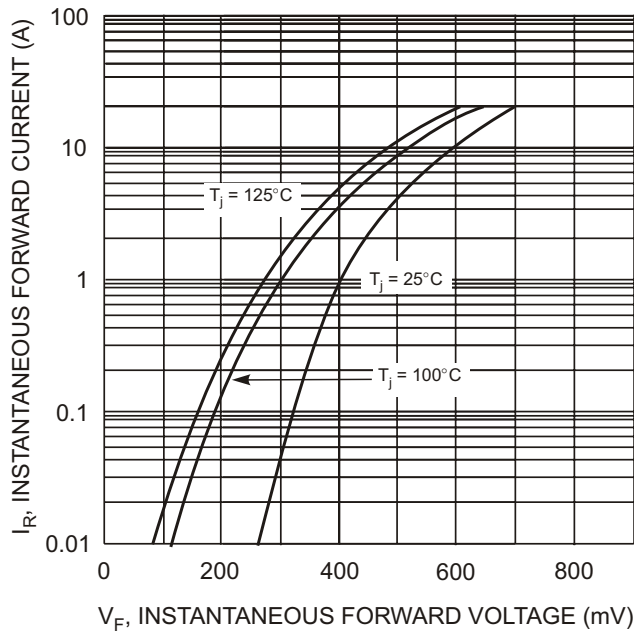


Fig. 1 Typical Forward Characteristics

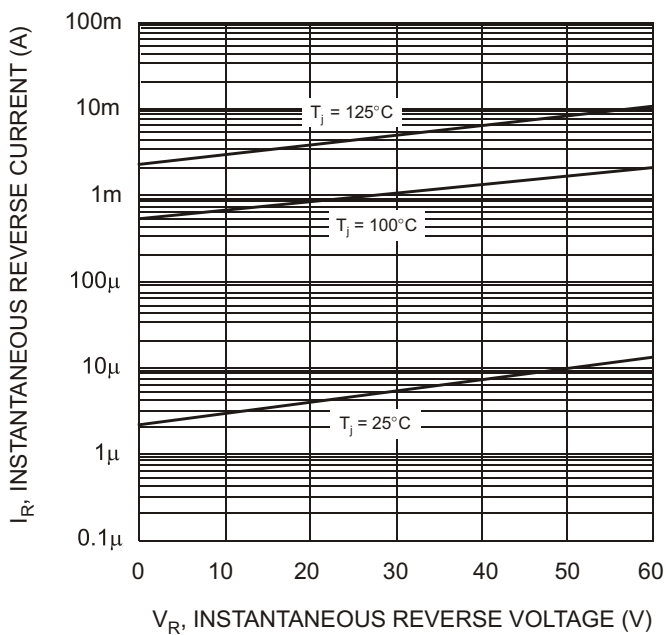


Fig. 2 Typical Reverse Characteristics

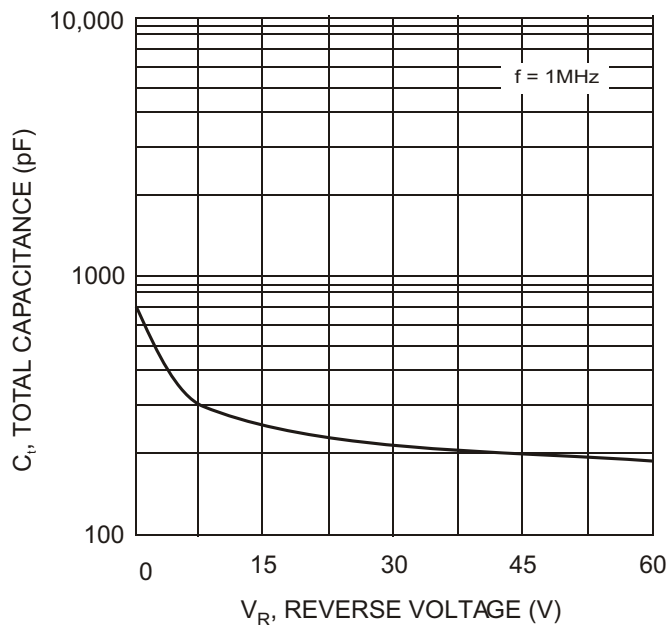
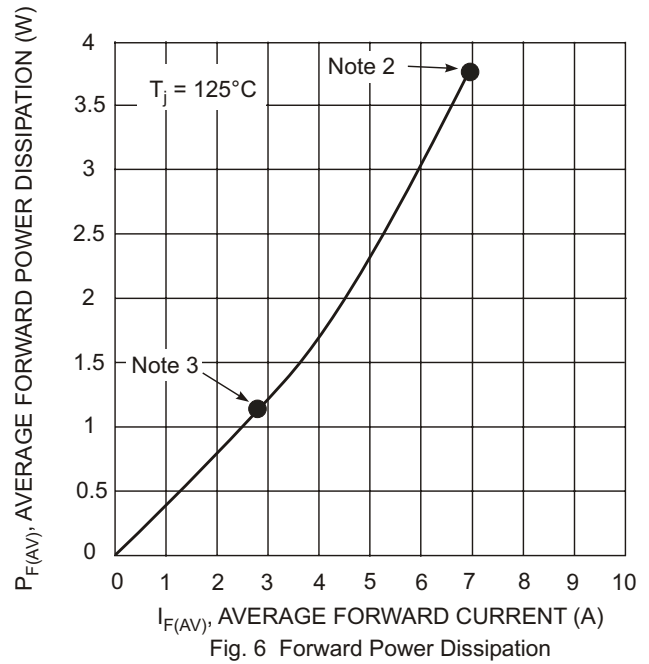
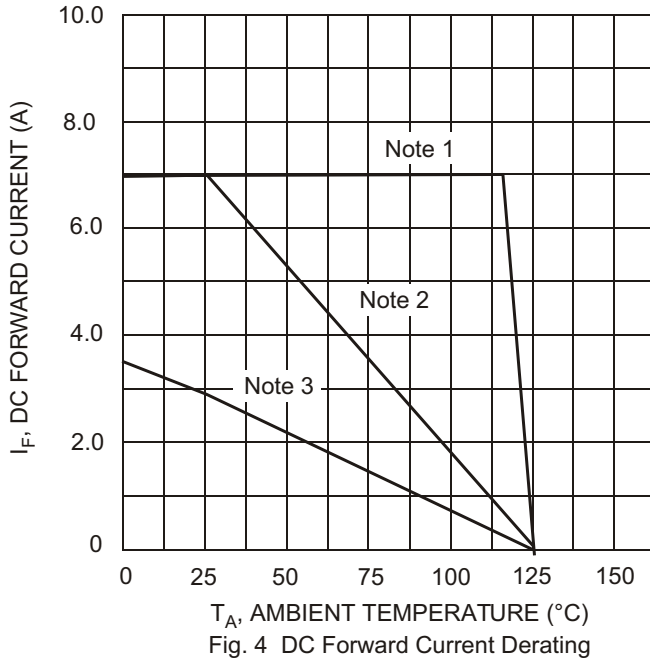


Fig. 3 Typical Capacitance vs. Reverse Voltage

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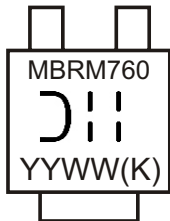


- Notes:
1. $T_A = T_{\text{SOLDERING POINT}}$, $R_{\theta JS} = 2.5^\circ\text{C/W}$, $R_{\theta SA} = 0^\circ\text{C/W}$.
 2. Device mounted on GETEK substrate, 2"x2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". $R_{\theta JA}$ in range of 20-35°C/W.
 3. Device mounted on FR-4 substrate, 2"x2", 2 oz. copper, single-sided, pad layout as per Diodes Inc. suggested pad layout document AP02001 which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>. $R_{\theta JA}$ in range of 75-100°C/W.
 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Ordering Information (Note 4)

Device	Packaging	Shipping
MBRM760-13	POWERMITE®3	5000/Tape & Reel

Marking Information



MBRM760 = Product type marking code
 DII = Manufacturers' code marking
 YYWW = Date code marking
 YY = Last digit of year ex: 2 for 2002
 WW = Week code 01 to 52
 (K) = Factory Designator

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POWERMITE is a registered trademark of Microsemi Corporation.